

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

Inventors: Wei Gao, and Yoshi Ono

Serial No: Not Yet Assigned

Filed: Herewith

Title: MOSFET STRUCTURES WITH
CONDUCTIVE NBO GATES

PATENT APPLICATION

Attorney Docket No.
SLA0805

Hon. Commissioner for Patents
Washington, D.C. 20231

INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. §1.97

Sir:

Listed on attached Form PTO-1449 is information submitted pursuant to
37 C.F.R. §1.56. A copy of each listed publication is submitted herewith.

Applicant respectfully requests that the listed information be considered by
the Examiner and made of record in the above-identified application.

September 30, 2003
(Date)

Respectfully submitted,



Matthew D. Rabdau
Reg. No. 43,026

Matthew D. Rabdau, Patent Attorney
Sharp Laboratories of America, Inc.
5750 NW Pacific Rim Boulevard
Camas, WA 98607
Telephone: (360) 834-8567
Facsimile: (360) 817-8505

